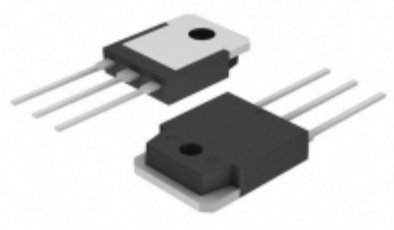


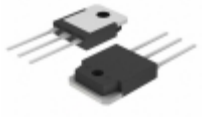


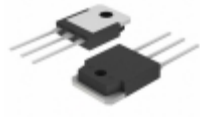

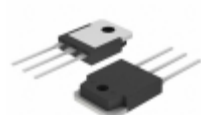

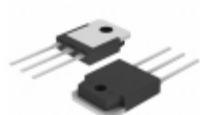
	FQA9N90C	
	Hersteller-Teilenummer:	FQA9N90C
	Hersteller / Marke:	AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung:	MOSFET N-CH 900V 9A TO-3P
	Datenblätter:	 FQA9N90C.pdf
	RoHs Status:	Bleifrei / RoHS-konform
<p>Image may be representation. See specs for product details.</p>	Lagerzustand:	New original, 14048 pcs Stock Available.
	Liefern von:	Hong Kong
	Versandweg:	DHL/Fedex/TNT/UPS/EMS

Spezifikationen

Teilenummer	FQA9N90C
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 900V 9A TO-3P
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	14048 pcs Stock
detaillierte Beschreibung	N-Channel 900V 9A (Tc) 280W (Tc) Through Hole TO-
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-3P-3, SC-65-3
Supplier Device-Gehäuse	TO-3P
Verlustleistung (max)	280W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	900V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	9A (Tc)
Rds On (Max) @ Id, Vgs	1.4 Ohm @ 4.5A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	58nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	2730pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)



















































FQA9N90C ist neu im Original, Suche FQA9N90C Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQA9N90C AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQA9N90C: Info@Y-IC.com

Sie können auch interessiert sein:

 FQA90N15_F109 Fairchild/ON Semiconductor FQA90N15_F109 Fairchild/ON Semiconductor	 FQA9N90 FAIRCHI FQA9N90 FAIRCHI	 FQA9N50 Fairchild/ON Semiconductor MOSFET N-CH 500V 9.6A TO-3P	 FQA9N90C-F109 AMI Semiconductor / ON Semiconductor MOSFET N-CH 900V 9A TO-3P
 FQA9P25 Fairchild/ON Semiconductor MOSFET P-CH 250V 10.5A TO-3P	 FQA9N90_F109 Fairchild/ON Semiconductor FQA9N90_F109 Fairchild/ON Semiconductor	 FQA9N90C Fairchild/ON Semiconductor MOSFET N-CH 900V 9A TO-3P	 FQA9N90-F109 AMI Semiconductor / ON Semiconductor MOSFET N-CH 900V 8.6A TO-3P

heiße Teile

Mehr

 FQA55N25	 FQA62N25C	 FQA62N25C	 D FQA65N06	 FQA65N06
 FQA65N20	 FQA65N20	 D FQA6N90C	 FQA70N10	 FQA70N10
 FQA70N15	 FQA70N15	 FQA7N80C	 FQA7N80C	 FQA8N100C
 D FQA8N100C	 FQA8N80C	 FQA8N80C	 FQA90N08	 FQA90N08
 FQA90N10V2	 FQA90N10V2	 FQA90N15	 FQA90N15	 FQA90N15_F109
 FQA9N90C	 FQA9N90C_F109	 D FQA9N90_F109	 FQAF10N80	 FQAF10N80
 FQAF11N40	 D FQAF11N40	 FQAF11N90	 FQAF11N90	 FQAF11N90C
 FQAF11N90C	 FQAF12P20	 FQAF12P20	 FQAF13N50	 FQAF13N80
 FQAF13N80	 FQAF14N30	 FQAF14N30	 D FQAF16N25	 FQAF16N25
 FQAF16N25C	 FQAF16N25C	 FQAF16N50	 FQAF16N50	 FQAF17N40

Contact us: Info@Y-IC.com

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